



#### 40V +175°C N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI3333-8

### **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub> Max	I <sub>D</sub> Max T <sub>C</sub> = +25°C	
40V	5.5mΩ @ V <sub>G</sub> S = 10V	71A	
400	7.9mΩ @ V <sub>GS</sub> = 4.5V	59A	

### **Description and Applications**

This MOSFET is designed to minimize the on-state resistance (RDS(ON)) yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- Backlighting
- Power management functions
- DC-DC converters

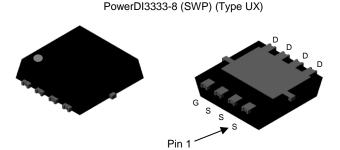
#### **Features and Benefits**

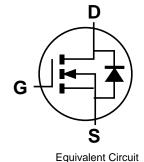
- Rated to +175°C Ideal for High Ambient Temperature Environments
- Low Rds(ON) Ensures On-State Losses are Minimized
- Excellent Qgd x RDS(ON) Product (FOM)
- Wettable Flank for Improved Optical Inspection
- 100% Unclamped Inductive Switching (UIS) Test in Production Ensures More Reliable and Robust End Application
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative.

https://www.diodes.com/quality/product-definitions/

#### **Mechanical Data**

- Package: PowerDI<sup>®</sup>3333-8
- Package Material: Molded Plastic, "Green" Molding Compound.
   UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish Matte Tin Annealed over Copper Leadframe;
   Solderable per MIL-STD-202, Method 208 (§3)
- Weight: 0.072 grams (Approximate)





Top View Bottom View

**Ordering Information** (Note 4)

Part Number	Pookogo	Packing		
Fait Number	Package	Qty.	Carrier	
DMTH45M5LFVW-7	PowerDI3333-8 (SWP) (Type UX)	2,000	Tape & Reel	
DMTH45M5LFVW-13	PowerDI3333-8 (SWP) (Type UX)	3,000	Tape & Reel	

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



## **Marking Information**

PowerDI3333-8 (SWP) (Type UX)



T4L = Product Type Marking Code

YYWW = Date Code Marking

YY = Last Two Digits of Year (ex: 23 = 2023)

WW = Week Code (01 to 53)

### **Maximum Ratings** (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	VDSS	40	V	
Gate-Source Voltage		Vgss	±20	V
Continuous Drain Current (Note 5), VGS = 10V	$T_{C} = +25^{\circ}C$ $T_{C} = +100^{\circ}C$	lD	71 50	А
Continuous Drain Current (Note 6), V <sub>GS</sub> = 10V	T <sub>A</sub> = +25°C T <sub>A</sub> = +100°C	I <sub>D</sub>	18 13	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	Ірм	284	Α	
Maximum Continuous Body Diode Forward Current (Note 5	Is	71	Α	
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cyc	I <sub>SM</sub>	284	Α	
Avalanche Current, L = 0.1mH	las	19.6	Α	
Avalanche Energy, L = 0.1mH	Eas	19.2	mJ	

# Thermal Characteristics

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 6) $T_A = +25$ °C		P <sub>D</sub>	3.5	W
Thermal Resistance, Junction to Ambient (Note 6)	Reja	42	°C/W	
Total Power Dissipation (Note 5)	PD	51	W	
Thermal Resistance, Junction to Case (Note 5)	Rejc	2.9	°C/W	
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +175	°C	

Notes:

<sup>5.</sup> Thermal resistance from junction to soldering point (on the exposed drain pad).6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.



# **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BVDSS	40	_	_	V	V <sub>G</sub> S = 0V, I <sub>D</sub> = 250µA	
Zero Gate Voltage Drain Current	IDSS	_	_	1	μA	V <sub>DS</sub> = 32V, V <sub>GS</sub> = 0V	
Gate-Source Leakage	Igss	_	_	±100	nA	$V_{GS} = \pm 20V$ , $V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	Vgs(TH)	1.2	_	2.3	V	$V_{DS} = V_{GS}$ , $I_D = 250\mu A$	
Static Drain-Source On-Resistance		_	3.9	5.5	0	$V_{GS} = 10V, I_D = 25A$	
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>	_	6.0	7.9	mΩ	$V_{GS} = 4.5V, I_D = 15A$	
Diode Forward Voltage	VsD	_	0.84	1.2	V	V <sub>G</sub> S = 0V, I <sub>S</sub> = 25A	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss	_	978	_		V <sub>DS</sub> = 20V, V <sub>GS</sub> = 0V f = 1MHz	
Output Capacitance	Coss	_	630	_	pF		
Reverse Transfer Capacitance	Crss	_	30	_			
Gate Resistance	Rg	_	1.5	_	Ω	$V_{DS} = 0V$ , $V_{GS} = 0V$ , $f = 1MHz$	
Total Gate Charge (V <sub>GS</sub> = 10V)	Qg	_	13.9	_		V <sub>DS</sub> = 20V, I <sub>D</sub> = 25A	
Total Gate Charge (VGS = 4.5V)	Qg	_	6.3	_	nC		
Gate-Source Charge	Qgs	_	3.6	_	nc		
Gate-Drain Charge	$Q_{gd}$	_	0.9	_			
Turn-On Delay Time	t <sub>D</sub> (ON)	_	2.8	_		$V_{DD} = 20V, V_{GS} = 10V$ $R_g = 3.5\Omega, I_D = 25A$	
Turn-On Rise Time	tR	_	3.1	_	20		
Turn-Off Delay Time	tD(OFF)	_	15.6	_	ns		
Turn-Off Fall Time	t <sub>F</sub>	_	5.5	_			
Body Diode Reverse Recovery Time	trr	_	59	_	ns	I_ 25A dl/dt 400A/	
Body Diode Reverse Recovery Charge	Q <sub>RR</sub>		50		nC	I <sub>F</sub> = 25A, dI/dt = 100A/μs	

Notes:

<sup>7.</sup> Short duration pulse test used to minimize self-heating effect. 8. Guaranteed by design. Not subject to production testing.



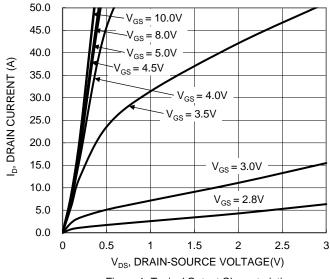


Figure 1. Typical Output Characteristic

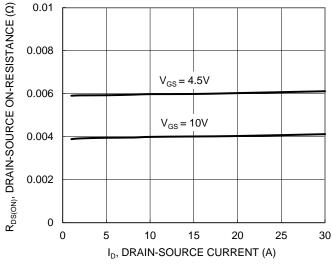


Figure 3. Typical On-Resistance vs. Drain Current and Gate Voltage

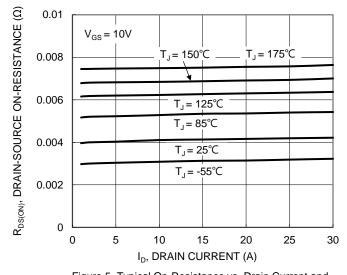


Figure 5. Typical On-Resistance vs. Drain Current and Junction Temperature

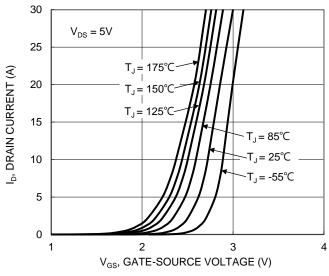


Figure 2. Typical Transfer Characteristic

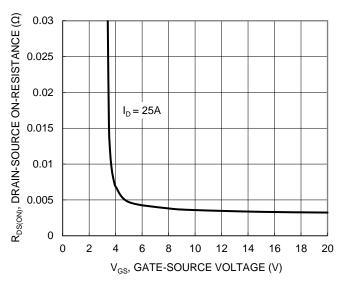


Figure 4. Typical Transfer Characteristic

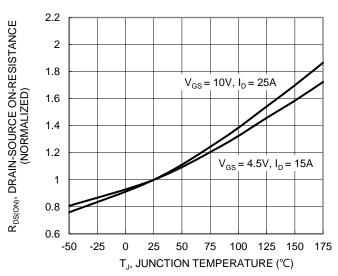


Figure 6. On-Resistance Variation with Junction Temperature



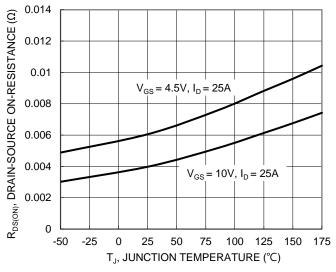


Figure 7. On-Resistance Variation with Junction **Temperature** 

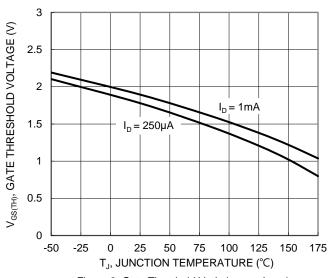


Figure 8. Gate Threshold Variation vs. Junction Temperature

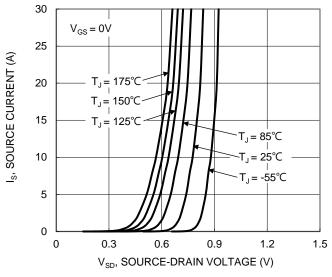


Figure 9. Diode Forward Voltage vs. Current

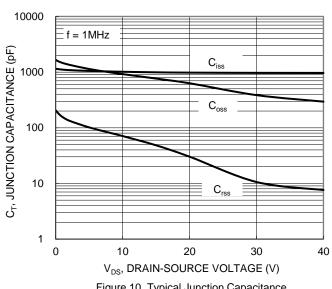


Figure 10. Typical Junction Capacitance

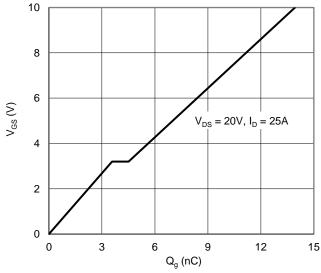


Figure 11. Gate Charge

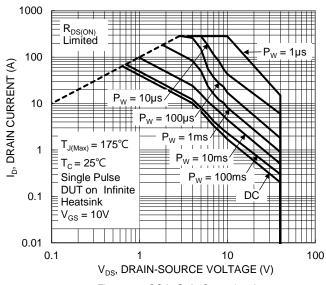


Figure 12. SOA, Safe Operation Area



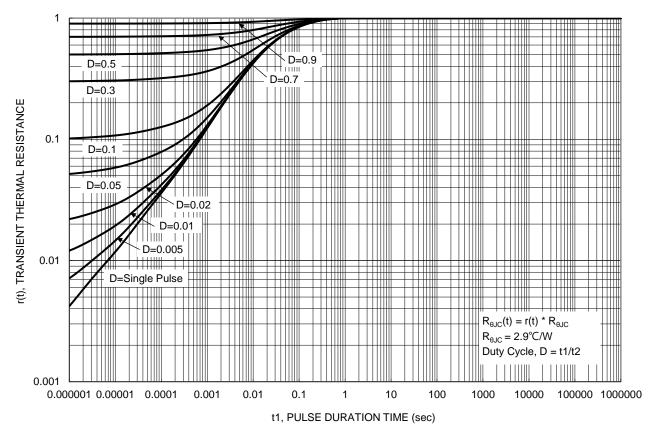


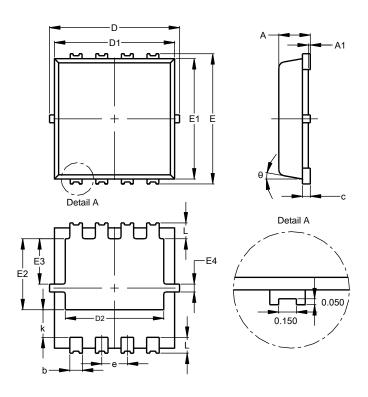
Figure 13. Transient Thermal Resistance



## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

### PowerDI3333-8 (SWP) (Type UX)

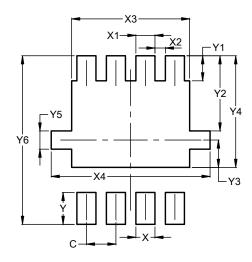


PowerDI3333-8 (SWP)					
(Type UX)					
Dim	Min	Max	Тур		
Α	0.75	0.85	0.80		
A1	0.00	0.05			
b	0.25	0.40	0.32		
С	0.10	0.25	0.15		
D	3.20	3.40	3.30		
D1	2.95	3.15	3.05		
D2	2.30	2.70	2.50		
Е	3.20	3.40	3.30		
E1	2.95	3.15	3.05		
E2	1.60	2.00	1.80		
E3	0.95	1.35	1.15		
E4	0.10	0.30	0.20		
е	_	_	0.65		
k	0.50	0.90	0.70		
L	0.30	0.50	0.40		
θ	0°	12°	10°		
All Dimensions in mm					

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### PowerDI3333-8 (SWP) (Type UX)



Dimensions	Value (in mm)
C	0.650
X	0.420
X1	0.420
X2	0.230
Х3	2.600
X4	3.500
Υ	0.700
Y1	0.550
Y2	1.650
Y3	0.600
Y4	2.450
Y5	0.400
Y6	3.700



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